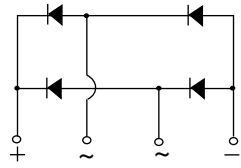
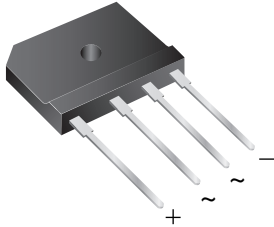


Single-Phase Single In-Line Bridge Rectifiers


Case Style GSIB-5S

FEATURES

- UL recognition file number E54214
- Thin single in-line package
- Glass passivated chip junction
- High surge current capability
- High case dielectric strength of 2500 V_{RMS}
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT
 HALOGEN
FREE

TYPICAL APPLICATIONS

General purpose use in AC/DC bridge full wave rectification for switching power supply, home appliances, office equipment, industrial automation applications.

MECHANICAL DATA

Case: GSIB-5S

Molding compound meets UL 94 V-0 flammability rating
 Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked on body

Mounting Torque: 10 cm-kg (8.8 in-lbs) maximum

Recommended Torque: 5.7 cm-kg (5 in-lbs)

PRIMARY CHARACTERISTICS	
Package	GSIB-5S
$I_{F(AV)}$	20 A
V_{RRM}	200 V, 400 V, 600 V, 800 V
I_{FSM}	240 A
I_R	10 μ A
V_F at $I_F = 7.5$ A	1.0 V
T_J max.	150 °C
Diode variations	In-Line

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted)						
PARAMETER	SYMBOL	GSIB2020N	GSIB2040N	GSIB2060N	GSIB2080N	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	200	400	600	800	V
Maximum RMS voltage	V_{RMS}	140	280	420	560	V
Maximum DC blocking voltage	V_{DC}	200	400	600	800	V
Maximum average forward rectified output current at	$T_C = 87$ °C	$I_{F(AV)}^{(1)}$				A
	$T_A = 25$ °C	$I_{F(AV)}^{(2)}$				
Peak forward surge current single sine-wave superimposed on rated load	I_{FSM}	240				A
Rating for fusing ($t < 8.3$ ms)	I^2t	240				A ² s
Operating junction and storage temperature range	T_J, T_{STG}	- 55 to + 150				°C

Notes

(1) Unit case mounted on aluminum plate heatsink

(2) Units mounted on PCB without heatsink



ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS	SYMBOL	GSIB2020N	GSIB2040N	GSIB2060N	GSIB2080N	UNIT
Maximum instantaneous forward voltage drop per diode	$I_F = 7.5\text{ A}$	V_F	1.0				V
Maximum DC reverse current at rated DC blocking voltage per diode	$T_A = 25\text{ }^\circ\text{C}$	I_R	10				μA
	$T_A = 125\text{ }^\circ\text{C}$		250				

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	SYMBOL	GSIB2020N	GSIB2040N	GSIB2060N	GSIB2080N	UNIT
Maximum thermal resistance	$R_{\theta JA}$ ⁽²⁾	22				$^\circ\text{C/W}$
	$R_{\theta JC}$ ⁽¹⁾	1.5				

Notes

- (1) Unit case mounted on aluminum plate heatsink
- (2) Units mounted on PCB without heatsink
- (3) Recommended mounting position is to bolt down on heatsink with silicone thermal compound for maximum heat transfer with #6 screw

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
GSIB2060N-M3/45	7.0	45	20	Tube

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

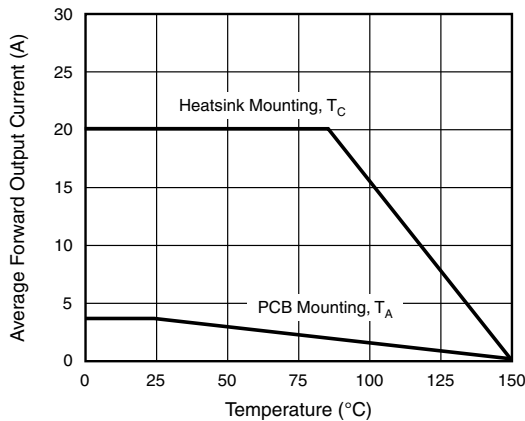


Fig. 1 - Derating Curve Output Rectified Current

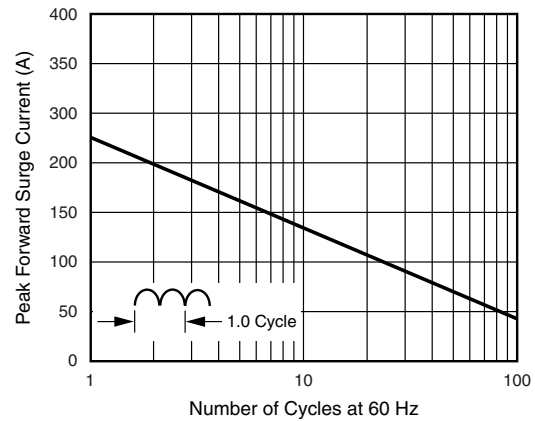


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

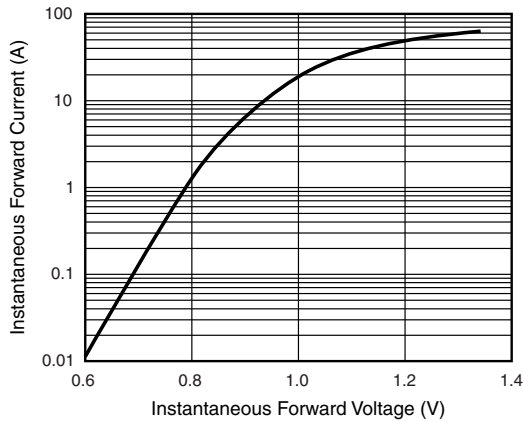


Fig. 3 - Typical Forward Characteristics Per Diode

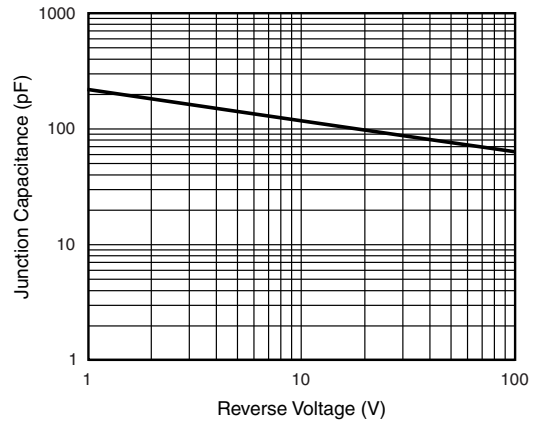


Fig. 5 - Typical Junction Capacitance Per Diode

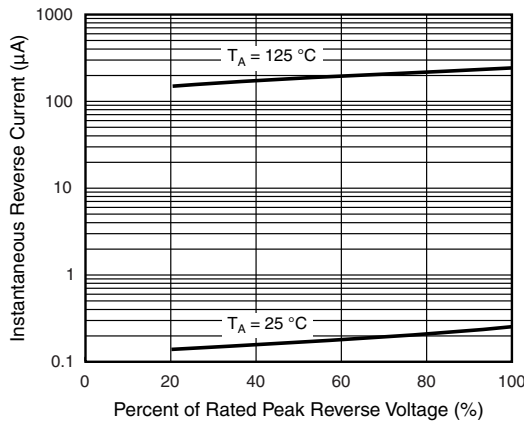


Fig. 4 - Typical Reverse Characteristics Per Diode

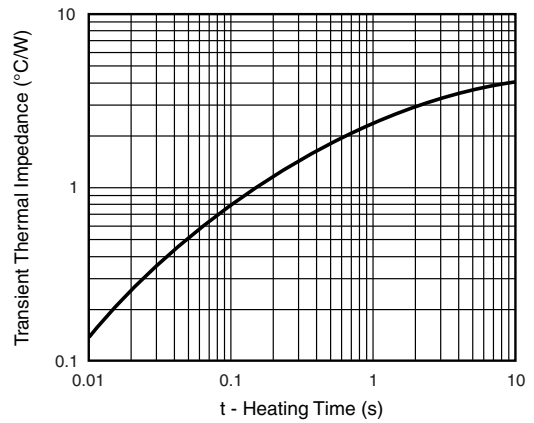


Fig. 6 - Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

Case Style GSIB-5S

